Low-power dual 2-input AND gate Rev. 10 — 8 March 2022

1. General description

The 74AUP2G08 is a dual 2-input AND gate. Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times. This device ensures very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- CMOS low power dissipation
- Low static power consumption; $I_{CC} = 0.9 \ \mu A$ (maximum)
- Latch-up performance exceeds 100 mA per JESD78 Class II
- Overvoltage tolerant inputs to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- IOFF circuitry provides partial Power-down mode operation
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.2 V to 1.95 V)
 - JESD8-5 (1.8 V to 2.7 V)
 - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

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3. Ordering information

	Table	1.	Ordering	information
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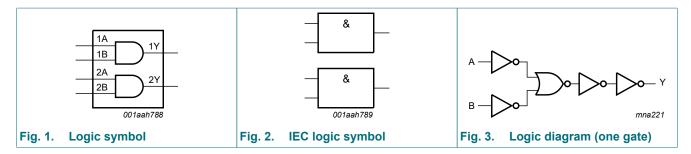
Type number	Package	Package								
	Temperature range	Name	Description	Version						
74AUP2G08DC	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	SOT765-1						
74AUP2G08GT	-40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 × 1.95 × 0.5 mm	SOT833-1						
74AUP2G08GM	-40 °C to +125 °C	XQFN8	plastic, extremely thin quad flat package; no leads; 8 terminals; body 1.6 × 1.6 × 0.5 mm	SOT902-2						
74AUP2G08GN	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.2 × 1.0 × 0.35 mm	SOT1116						
74AUP2G08GS	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1.0 × 0.35 mm	SOT1203						
74AUP2G08GX	-40 °C to +125 °C	X2SON8	plastic thermal enhanced extremely thin small outline package; no leads; 8 terminals; body 1.35 × 0.8 × 0.35 mm	SOT1233						

4. Marking

Table 2. Marking						
Type number	Marking code[1]					
74AUP2G08DC	p08					
74AUP2G08GT	p08					
74AUP2G08GM	p08					
74AUP2G08GN	pE					
74AUP2G08GS	pE					
74AUP2G08GX	pE					

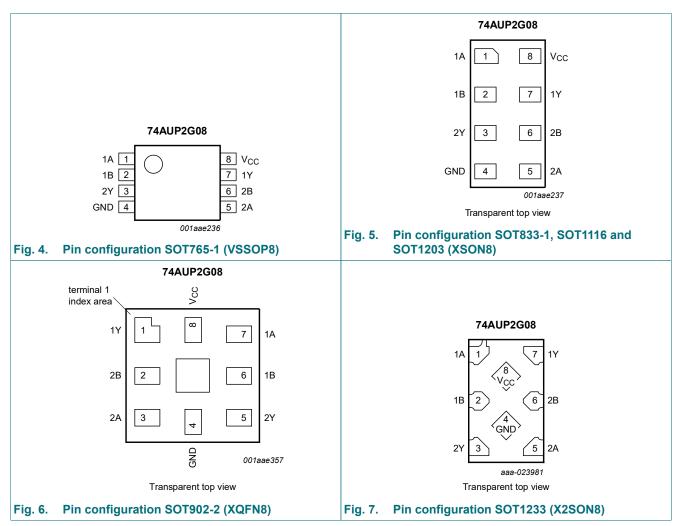
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



74AUP2G08

6. Pinning information



6.1. Pinning

6.2. Pin description

Table 3. Pin description

Symbol	Pin	Description	
	SOT765-1, SOT833-1, SOT1116, SOT1203 and SOT1233	SOT902-2	
1A, 2A	1, 5	7, 3	data input
1B, 2B	2, 6	6, 2	data input
GND	4	4	ground (0 V)
1Y, 2Y	7, 3	1, 5	data output
V _{CC}	8	8	supply voltage

7. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level.

Input	Output	
nA	nB	nY
L	L	L
L	Н	L
н	L	L
Н	Н	Н

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+4.6	V
VI	input voltage		[1]	-0.5	+4.6	V
Vo	output voltage	Active mode and Power-down mode	[1]	-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V		-50	-	mA
I _{OK}	output clamping current	V _O < 0 V		-50	-	mA
I _O	output current	$V_{O} = 0 V$ to V_{CC}		-	±20	mA
I _{CC}	supply current			-	+50	mA
I _{GND}	ground current			-50	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C				
		SOT765-1, SOT833-1, SOT1116, SOT1203 and SOT1233	[2]	-	250	mW
		SOT1233 package	[3]	-	300	mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT765-1 (VSSOP8) package: P_{tot} derates linearly with 4.9 mW/K above 99 °C.

For SOT833-1 (XSON8) package: P_{tot} derates linearly with 3.1 mW/K above 68 °C.

For SOT902-2 (XQFN8) packages: P_{tot} derates linearly with 4.1 mW/K above 89 °C.

For SOT1116 (XSON8) package: Ptot derates linearly with 4.2 mW/K above 90 °C.

For SOT1203 (XSON8) package: P_{tot} derates linearly with 3.6 mW/K above 81 °C.

[3] For SOT1233 (X2SON8) package: P_{tot} derates linearly with 7.7 mW/K above 118 °C.

9. Recommended operating conditions

Table 6. Operating conditions Conditions Symbol Parameter Min V_{CC} supply voltage 0.8 VI input voltage 0 Vo output voltage 0 Active mode Power-down mode; V_{CC} = 0 V 0 ambient temperature -40 Tamb Δt/ΔV input transition rise and fall rate V_{CC} = 0.8 V to 3.6 V -

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Max

3.6

3.6

V_{CC}

3.6

+125

200

Unit

V

V

V

V

°C

ns/V

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
T _{amb} = 2	5 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.65 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V_{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{он}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}				
		I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.75 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.32	-	-	V
		$I_{\rm O}$ = -2.3 mA; $V_{\rm CC}$ = 2.3 V	2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		$I_{\rm O}$ = -2.7 mA; $V_{\rm CC}$ = 3.0 V	2.72	-	-	V
		I_{O} = -4.0 mA; V_{CC} = 3.0 V	2.6	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V
I _I	input leakage current	V_I = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.1	μA
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.2	μA
ΔI _{OFF}	additional power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.2	μA
l _{cc}	supply current	V_{I} = GND or V_{CC} ; I_{O} = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	0.5	μA
ΔI _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}; $ [1] $V_{CC} = 3.3 \text{ V}; \text{ per pin}$	-	-	40	μA
CI	input capacitance	V_{CC} = 0 V to 3.6 V; V _I = GND or V _{CC}	-	0.6	-	pF
Co	output capacitance	$V_0 = GND; V_{CC} = 0 V$	-	1.3	-	pF

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Low-power dual 2-input AND gate

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
T _{amb} = -4	0 °C to +85 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	$0.65 \times V_{CC}$	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{ОН}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	$0.7 \times V_{CC}$	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.03	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.30	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.97	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.85	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.67	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.55	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_0 = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.45	V
l _i	input leakage current	V_I = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.5	μA
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.5	μA
ΔI _{OFF}	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.6	μA
lcc	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.9	μA
∆l _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 V; I_{O} = 0 A;$ [1] $V_{CC} = 3.3 V;$ per pin	-	-	50	μA

Low-power dual 2-input AND gate

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
T _{amb} = -4	0 °C to +125 °C					
VIH	HIGH-level input voltage	V _{CC} = 0.8 V	0.75 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	$0.70 \times V_{CC}$	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.25 × V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.6 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.17	-	-	V
		I_0 = -2.3 mA; V_{CC} = 2.3 V	1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.67	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.40	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.30	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.33 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.36	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.50	V
l _l	input leakage current	V_I = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.75	μA
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.75	μA
∆I _{OFF}	additional power-off leakage current	$V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.75	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	1.4	μA
ΔI _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A};$ [1] $V_{CC} = 3.3 \text{ V}; \text{ per pin}$	-	-	75	μA

[1] One input at V_{CC} - 0.6 V, other inputs at V_{CC} or GND.

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 9.

Symbol	Parameter	Conditions	T,	_{amb} = 25 °	°C	T _{an} -40 °C te	_{nb} = o +85 °C	T _{ar} -40 °C to	_{nb} =) +125 °C	Unit
			Min	Typ[1]	Мах	Min	Max	Min	Max	
C _L = 5 p	F									
t _{pd}	propagation	nA, nB to nY; see Fig. 8 [2]								
	delay	V _{CC} = 0.8 V	-	17.0	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.6	5.1	10.8	2.1	11.7	2.1	12.9	ns
		V _{CC} = 1.4 V to 1.6 V	1.6	3.7	6.5	1.5	7.5	1.5	8.3	ns
		V _{CC} = 1.65 V to 1.95 V	1.3	3.0	5.2	1.3	6.1	1.3	6.7	ns
		V _{CC} = 2.3 V to 2.7 V	1.1	2.4	4.0	1.0	4.8	1.0	5.3	ns
		V _{CC} = 3.0 V to 3.6 V	1.0	2.2	3.5	0.9	4.3	0.9	4.8	ns
C _L = 10	pF								•	-
t _{pd}	propagation	nA, nB to nY; see Fig. 8 [2]								
	delay	V _{CC} = 0.8 V	-	20.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.4	6.0	12.5	2.2	13.6	2.2	15.0	ns
		V _{CC} = 1.4 V to 1.6 V	2.0	4.3	7.6	1.8	8.9	1.8	9.8	ns
		V _{CC} = 1.65 V to 1.95 V	1.7	3.6	6.1	1.6	7.2	1.6	7.9	ns
		V _{CC} = 2.3 V to 2.7 V	1.4	2.9	4.8	1.3	5.7	1.3	6.3	ns
		V _{CC} = 3.0 V to 3.6 V	1.3	2.7	4.2	1.2	4.7	1.2	5.2	ns
C _L = 15	pF									
t _{pd}	propagation	nA, nB to nY; see Fig. 8 [2]								
	delay	V _{CC} = 0.8 V	-	24.1	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.4	6.8	14.2	3.1	15.7	3.1	17.3	ns
		V _{CC} = 1.4 V to 1.6 V	2.3	4.9	8.6	2.1	10.1	2.1	11.2	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	4.0	6.9	1.8	8.2	1.8	9.0	ns
		V _{CC} = 2.3 V to 2.7 V	1.7	3.4	5.5	1.6	6.5	1.6	7.2	ns
		V _{CC} = 3.0 V to 3.6 V	1.5	3.1	4.8	1.5	5.9	1.5	6.5	ns
C _L = 30	pF									1
t _{pd}	propagation	nA, nB to nY; see Fig. 8 [2]								
	delay	V _{CC} = 0.8 V	-	34.4	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.6	9.1	19.4	4.1	21.8	4.1	24.0	ns
		V _{CC} = 1.4 V to 1.6 V	3.4	6.4	11.5	2.9	13.6	2.9	15.0	ns
		V _{CC} = 1.65 V to 1.95 V	2.6	5.3	9.1	2.4	10.9	2.4	12.1	ns
		V _{CC} = 2.3 V to 2.7 V	2.3	4.5	7.2	2.2	8.6	2.2	9.5	ns
		V _{CC} = 3.0 V to 3.6 V	2.2	4.2	6.2	2.1	7.5	2.1	8.3	ns

Low-power dual 2-input AND gate

Symbol	Parameter	arameter Conditions		T _{amb} = 25 °C		T _{amb} = -40 °C to +85 °C		T _{amb} = -40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
C _L = 5 p	F, 10 pF, 15 p	F and 30 pF								
C _{PD}	power dissipation	$f_i = 1 \text{ MHz};$ [3] V ₁ = GND to V _{CC}								
	capacitance	V _{CC} = 0.8 V	-	2.5	-	-	-	-	-	pF
		V _{CC} = 1.1 V to 1.3 V	-	2.6	-	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	2.7	-	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	2.8	-	-	-	-	-	pF
		V _{CC} = 2.3 V to 2.7 V	-	3.2	-	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	3.7	-	-	-	-	-	pF

All typical values are measured at nominal V_{CC}. [1]

[2]

 t_{pd} is the same as t_{PLH} and t_{PHL} . C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where: [3]

f_i = input frequency in MHz;

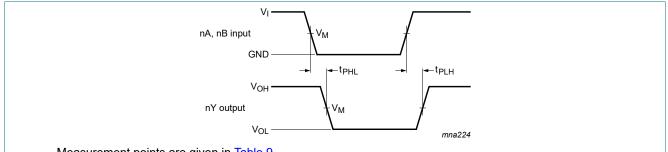
 f_o = output frequency in MHz;

 C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching; $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of outputs.

11.1. Waveforms and test circuit



Measurement points are given in Table 9.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 8. The data input (nA or nB) to output (nY) propagation delays

Table 9. Measurement points

Supply voltage	Output	Input				
V _{cc}	V _M	V _M	VI	t _r = t _f		
0.8 V to 3.6 V	0.5 × V _{CC}	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns		

Low-power dual 2-input AND gate

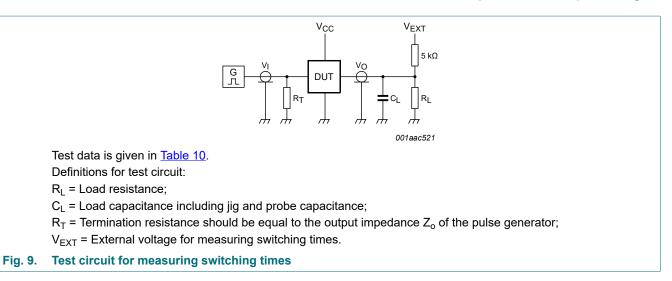


Table 10. Test data

Supply voltage	Load		V _{EXT}		
V _{cc}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	$2 \times V_{CC}$

[1] For measuring enable and disable times $R_L = 5 k\Omega$.

For measuring propagation delays, setup and hold times and pulse width R_L = 1 M Ω .

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12. Package outline

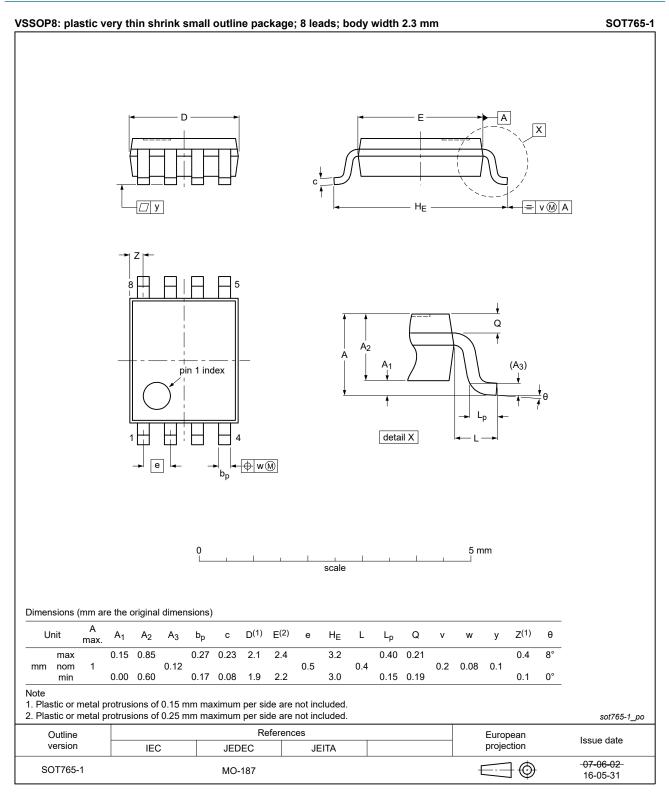


Fig. 10. Package outline SOT765-1 (VSSOP8)

Low-power dual 2-input AND gate

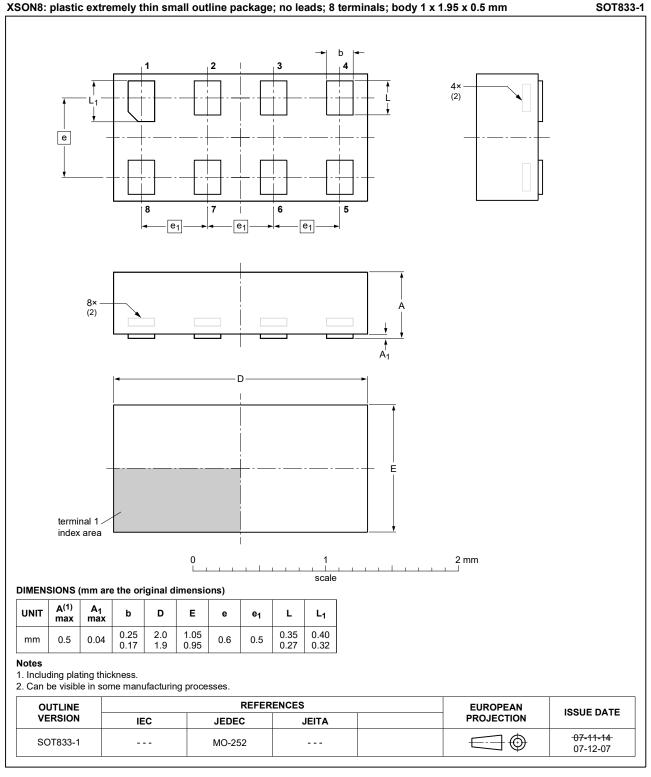
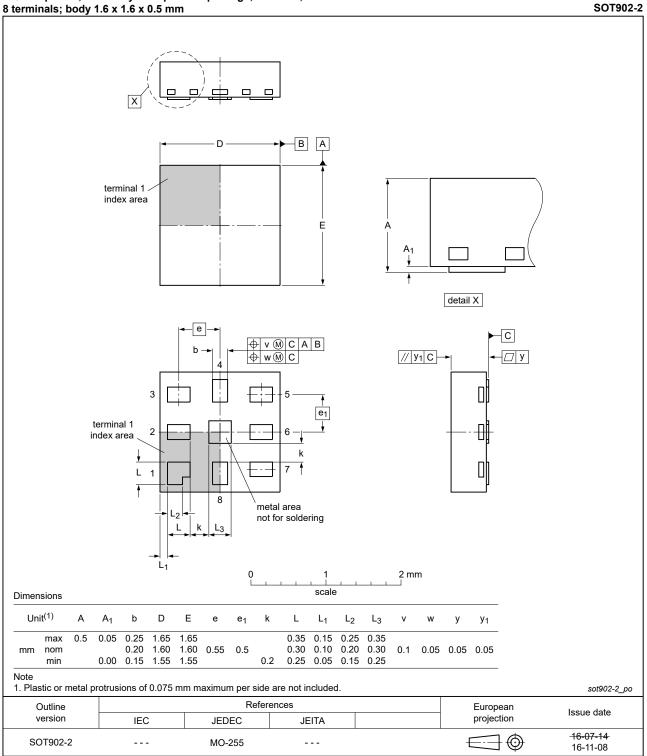


Fig. 11. Package outline SOT833-1 (XSON8)

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XQFN8: plastic, extremely thin quad flat package; no leads; 8 terminals; body 1.6 x 1.6 x 0.5 mm

Fig. 12. Package outline SOT902-2 (XQFN8)

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XSON8: extremely thin small outline package; no leads; 8 terminals; body 1.2 x 1.0 x 0.35 mm

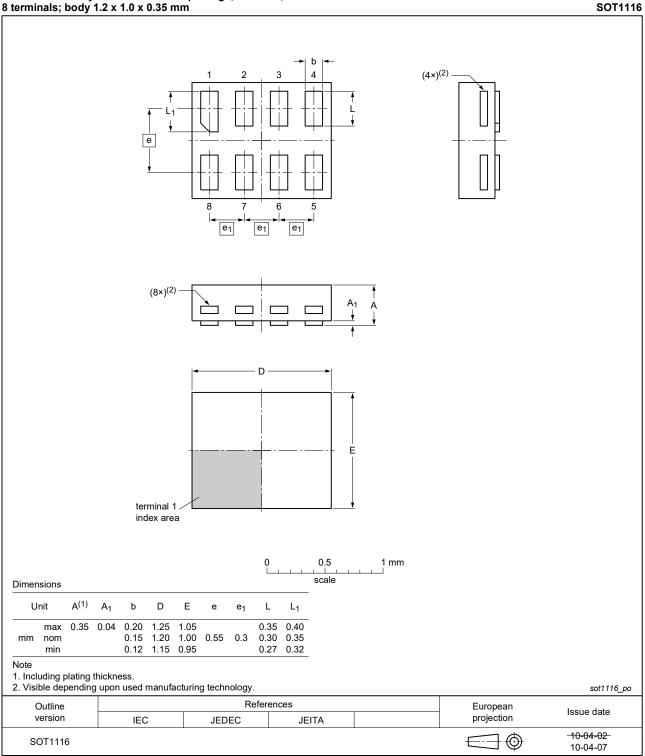
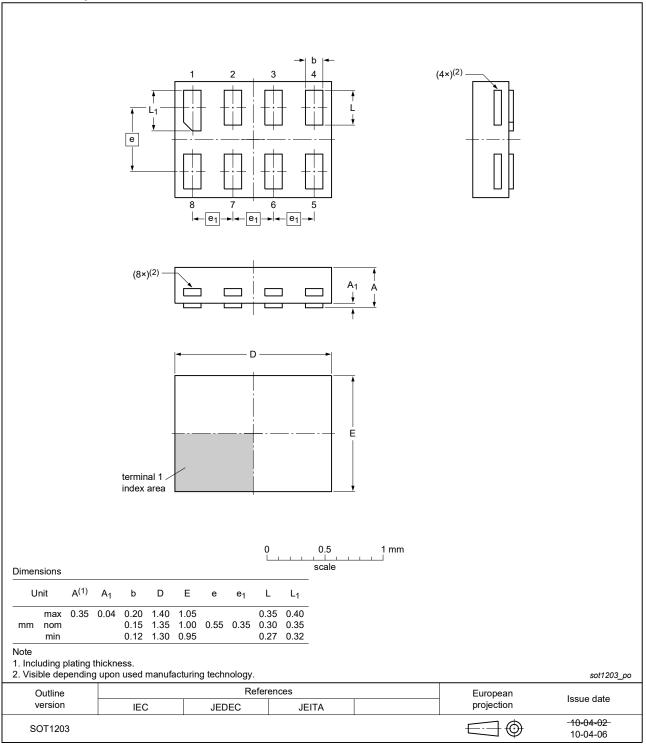


Fig. 13. Package outline SOT1116 (XSON8)

SOT1203

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XSON8: extremely thin small outline package; no leads; 8 terminals; body 1.35 x 1.0 x 0.35 mm





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X2SON8: plastic thermal enhanced extremely thin small outline package; no leads; 8 terminals; body 1.35 x 0.8 x 0.35 mm SOT1233 Х A В D E A_1 detail X pin 1 index area е е С b⊸ ___ y ⊕ w∭ C (6x) 3 pin 1 index area D_h ٠ L (6x) 7 7 |6 b₁ 5 // y1 C (2x) e₁ 0 1 mm scale Dimensions (mm are the original dimensions) Unit А A_1 b b₁ D D_h Е L v е e₁ w у У1 0.85 0.35 0.04 0.25 1.40 0.27 0.27 max 0.20 0.15 1.35 0.22 0.80 0.5 0.54 0.22 0.1 0.05 0.05 0.05 mm nom 0.32 (ref) 0.30 0.00 0.15 1.30 0.17 0.17 min 0.75 sot1233_po European projection References Outline Issue date version IEC JEDEC JEITA 16-04-21 \bigcirc SOT1233 ____ 17-01-05

Fig. 15. Package outline SOT1233 (X2SON8)

13. Abbreviations

Table 11. Abbreviations				
Acronym	Description			
CDM	Charged Device Model			
DUT	Device Under Test			
ESD	ElectroStatic Discharge			
НВМ	Human Body Model			
MM	Machine Model			

14. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74AUP2G08 v.10	20220308	Product data sheet	-	74AUP2G08 v.9	
Modifications:	<u>Section 1</u> and	74AUP2G08GF (SOT1 d <u>Section 2</u> updated. ting values for P _{tot} total			
74AUP2G08 v.9	20170703	Product data sheet	-	74AUP2G08 v.8	
Modifications:	of Nexperia. • Legal texts h • <u>Fig. 7</u> and <u>Fig</u>	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Fig. 7 and Fig. 15 (drawings SOT1233/X2SON8) updated. Type number 74AUP2G08GD removed. 			
74AUP2G08 v.8	20161028	Product data sheet	-	74AUP2G08 v.7	
Modifications:	Added type n	Added type number 74AUP2G08GX (SOT1233/X2SON8)			
74AUP2G08 v.7	20130118	Product data sheet	-	74AUP2G08 v.6	
Modifications:	For type num	For type number 74AUP2G08GD XSON8U has changed to XSON8.			
74AUP2G08 v.6	20120607	Product data sheet	-	74AUP2G08 v.5	
74AUP2G08 v.5	20111201	Product data sheet	-	74AUP2G08 v.4	
74AUP2G08 v.4	20101109	Product data sheet	-	74AUP2G08 v.3	
74AUP2G08 v.3	20080529	Product data sheet	-	74AUP2G08 v.2	
74AUP2G08 v.2	20080407	Product data sheet	-	74AUP2G08 v.1	
74AUP2G08 v.1	20061006	Product data sheet	-	-	

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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